

ON5088

NPN wideband silicon germanium RF transistor

Rev. 3 — 12 December 2012

Product data sheet

1. Product profile

1.1 General description

NPN silicon germanium microwave transistor for high speed, low noise applications in a plastic, 4-pin dual-emitter SOT343F package.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

1.2 Features and benefits

- Low noise high gain microwave transistor
- High maximum stable gain 27 dB at 1.8 GHz
- 110 GHz f_T silicon germanium technology

1.3 Applications

- 2nd and 3rd LNA stage in DBS LNBS
- Satellite radio
- Low noise amplifiers for microwave communications systems
- WLAN and WiMAX applications
- Analog/digital cordless applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CB}	collector-base voltage	open emitter	-	-	10	V
V_{CE}	collector-emitter voltage	open base	-	-	3.0	V
		shorted base	-	-	10	V
V_{EB}	emitter-base voltage	open collector	-	-	1.0	V
I_C	collector current		-	25	40	mA
P_{tot}	total power dissipation	$T_{sp} \leq 90\text{ °C}$	1	-	136	mW
h_{FE}	DC current gain	$I_C = 10\text{ mA}$; $V_{CE} = 2\text{ V}$; $T_j = 25\text{ °C}$	160	280	400	
C_{CBS}	collector-base capacitance	$V_{CB} = 2\text{ V}$; $f = 1\text{ MHz}$	-	70	-	fF



Table 1. Quick reference data ...continued

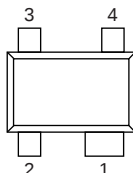
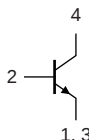
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_T	transition frequency	$I_C = 25\text{ mA}$; $V_{CE} = 2\text{ V}$; $f = 2\text{ GHz}$; $T_{amb} = 25\text{ °C}$	-	55	-	GHz
$G_{p(max)}$	maximum power gain	$I_C = 25\text{ mA}$; $V_{CE} = 2\text{ V}$; $f = 12\text{ GHz}$; $T_{amb} = 25\text{ °C}$	[2] -	13	-	dB
NF	noise figure	$I_C = 5\text{ mA}$; $V_{CE} = 2\text{ V}$; $f = 12\text{ GHz}$; $\Gamma_S = \Gamma_{opt}$; $T_{amb} = 25\text{ °C}$	-	1.1	-	dB

[1] T_{sp} is the temperature at the solder point of the emitter lead.

[2] $G_{p(max)}$ is the maximum power gain, if $K > 1$. If $K < 1$ then $G_{p(max)}$ = Maximum Stable Gain (MSG).

2. Pinning information

Table 2. Discrete pinning

Pin	Description	Simplified outline	Graphic symbol
1	emitter		
2	base		
3	emitter		
4	collector		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
ON5088	-	plastic surface-mounted flat pack package; reverse pinning; 4 leads	SOT343F

4. Marking

Table 4. Marking

Type number	Marking	Description
ON5088	*6N	* = p : made in Hong Kong * = t : made in Malaysia * = W : made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CB}	collector-base voltage	open emitter	-	10	V
V_{CE}	collector-emitter voltage	open base	-	3.0	V
		shorted base	-	10	V
V_{EB}	emitter-base voltage	open collector	-	1.0	V
I_C	collector current		-	40	mA
P_{tot}	total power dissipation	$T_{sp} \leq 90\text{ °C}$	[1]	136	mW
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	150	°C

[1] T_{sp} is the temperature at the solder point of the emitter lead.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		440	K/W

7. Characteristics

Table 7. Characteristics

$T_j = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 2.5\text{ }\mu\text{A}$; $I_E = 0\text{ mA}$	10	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 1\text{ mA}$; $I_B = 0\text{ mA}$	3.0	-	-	V
I_C	collector current		-	25	40	mA
I_{CBO}	collector-base cut-off current	$I_E = 0\text{ mA}$; $V_{CB} = 4.5\text{ V}$	-	-	100	nA
h_{FE}	DC current gain	$I_C = 10\text{ mA}$; $V_{CE} = 2\text{ V}$	160	280	400	
C_{CES}	collector-emitter capacitance	$V_{CB} = 2\text{ V}$; $f = 1\text{ MHz}$	-	268	-	fF
C_{EBS}	emitter-base capacitance	$V_{EB} = 0.5\text{ V}$; $f = 1\text{ MHz}$	-	400	-	fF
C_{CBS}	collector-base capacitance	$V_{CB} = 2\text{ V}$; $f = 1\text{ MHz}$	-	70	-	fF
f_T	transition frequency	$I_C = 25\text{ mA}$; $V_{CE} = 2\text{ V}$; $f = 2\text{ GHz}$; $T_{amb} = 25\text{ °C}$	-	55	-	GHz
$G_{p(max)}$	maximum power gain	$I_C = 25\text{ mA}$; $V_{CE} = 2\text{ V}$; $T_{amb} = 25\text{ °C}$	[1]			
		$f = 1.8\text{ GHz}$	-	27	-	dB
		$f = 12\text{ GHz}$	-	13	-	dB
$ s_{21} ^2$	insertion power gain	$I_C = 25\text{ mA}$; $V_{CE} = 2\text{ V}$; $T_{amb} = 25\text{ °C}$				
		$f = 1.8\text{ GHz}$	-	25.4	-	dB
		$f = 12\text{ GHz}$	-	9.3	-	dB

Table 7. Characteristics ...continued $T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

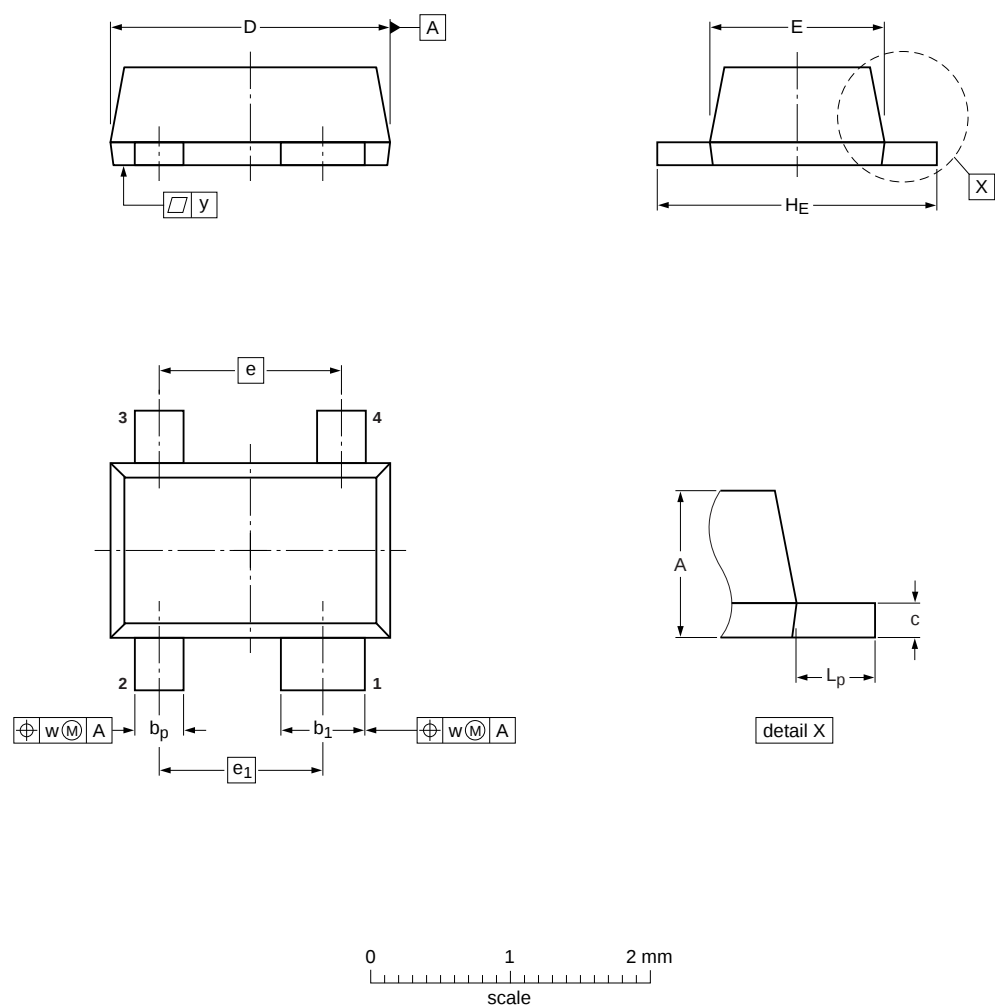
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
NF	noise figure	$I_C = 5\text{ mA}; V_{CE} = 2\text{ V}; \Gamma_S = \Gamma_{opt}; T_{amb} = 25\text{ }^{\circ}\text{C}$				
		$f = 1.8\text{ GHz}$	-	0.43	-	dB
		$f = 12\text{ GHz}$	-	1.1	-	dB
G_{ass}	associated gain	$I_C = 5\text{ mA}; V_{CE} = 2\text{ V}; \Gamma_S = \Gamma_{opt}; T_{amb} = 25\text{ }^{\circ}\text{C}$				
		$f = 1.8\text{ GHz}$	-	22	-	dB
		$f = 12\text{ GHz}$	-	10	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression	$I_C = 25\text{ mA}; V_{CE} = 2\text{ V}; Z_S = Z_L = 50\text{ }\Omega; T_{amb} = 25\text{ }^{\circ}\text{C}; f = 1.8\text{ GHz}$	-	9	-	dBm
IP3	third-order intercept point	$I_C = 25\text{ mA}; V_{CE} = 2\text{ V}; Z_S = Z_L = 50\text{ }\Omega; T_{amb} = 25\text{ }^{\circ}\text{C}; f_2 = f_1 + 1\text{ MHz}; f_1 = 1.8\text{ GHz}$	-	17	-	dBm

[1] $G_{p(max)}$ is the maximum power gain, if $K > 1$. If $K < 1$ then $G_{p(max)} = MSG$.

8. Package outline

Plastic surface-mounted flat pack package; reverse pinning; 4 leads

SOT343F



DIMENSIONS (mm are the original dimensions)												
UNIT	A _{max}	b _p	b ₁	c	D	E	e	e ₁	H _E	L _p	w	y
mm	0.75 0.65	0.4 0.3	0.7 0.5	0.25 0.10	2.2 1.8	1.35 1.15	1.3	1.15	2.2 2.0	0.48 0.38	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT343F						05-07-12 06-03-16

Fig 1. Package outline SOT343F

9. Abbreviations

Table 8. Abbreviations

Acronym	Description
DBS	Direct Broadcast Satellite
DC	Direct Current
DRO	Dielectric Resonator Oscillator
LNA	Low Noise Amplifier
LNB	Low Noise Block
NPN	Negative-Positive-Negative
RF	Radio Frequency
WLAN	Wireless Local Area Network
WiMAX	Worldwide Interoperability for Microwave Access

10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
ON5088 v.3	20121212	Product data sheet	-	ON5088 v.2
Modifications:	• Table 1 on page 1: some changes have been made. • Table 5 on page 3: some changes have been made. • Table 7 on page 3: The minimum value for $V_{(BR)CEO}$ has been changed.			
ON5088 v.2	20111222	Product data sheet	-	ON5088 v.1
ON5088 v.1	20100422	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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